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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/944,985	08/30/2001	Arup Bhattacharyya	1303.023US1	1905
21186 75	590 05/19/2005		EXAM	INER
SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A.			TRAN, THIEN F	
P.O. BOX 2938 MINNEAPOLIS, MN 55402-0938			ART UNIT	PAPER NUMBER
			2811	
			DATE MAILED: 05/19/2005	

Please find below and/or attached an Office communication concerning this application or proceeding.

	Application No.	Applicant(s)			
	09/944,985	BHATTACHARYYA, ARUP			
Office Action Summary	Examiner	Art Unit			
	Thien F. Tran	2811			
The MAILING DATE of this communication Period for Reply	appears on the cover sheet w	ith the correspondence address			
A SHORTENED STATUTORY PERIOD FOR RETHE MAILING DATE OF THIS COMMUNICATION Extensions of time may be available under the provisions of 37 CFI after SIX (6) MONTHS from the mailing date of this communication If the period for reply specified above is less than thirty (30) days, and If NO period for reply is specified above, the maximum statutory period for reply within the set or extended period for reply will, by stany reply received by the Office later than three months after the meanned patent term adjustment. See 37 CFR 1.704(b).	ON. R 1.136(a). In no event, however, may a . I reply within the statutory minimum of thir riod will apply and will expire SIX (6) MOI atute, cause the application to become Al	reply be timely filed ty (30) days will be considered timely. NTHS from the mailing date of this communication. BANDONED (35 U.S.C. § 133).			
Status					
1) Responsive to communication(s) filed on 2	7 April 2005.				
	This action is non-final.				
	Since this application is in condition for allowance except for formal matters, prosecution as to the ments is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.				
Disposition of Claims					
4) ⊠ Claim(s) <u>1-6,8-61,63-78,80-84 and 117-13</u> 4a) Of the above claim(s) <u>See Continuation</u> 5) ⊠ Claim(s) <u>125-127 and 132</u> is/are allowed. 6) ⊠ Claim(s) <u>1,2,4,14,18,19,56,57,59,63,73,74</u> 7) □ Claim(s) is/are objected to. 8) □ Claim(s) are subject to restriction and Application Papers	Sheet is/are withdrawn from ,76,80 and 84 is/are rejected.	consideration.			
Application Papers					
9) ☐ The specification is objected to by the Exar 10) ☐ The drawing(s) filed on is/are: a) ☐ Applicant may not request that any objection to	accepted or b)□ objected to				
Replacement drawing sheet(s) including the co	· · · · · · · · · · · · · · · · · · ·				
Priority under 35 U.S.C. § 119					
12) Acknowledgment is made of a claim for force a) All b) Some * c) None of: 1. Certified copies of the priority docum 2. Certified copies of the priority docum 3. Copies of the certified copies of the application from the International But * See the attached detailed Office action for a	nents have been received. nents have been received in A priority documents have beer reau (PCT Rule 17.2(a)).	Application No n received in this National Stage			
Attachment(s) 1) Notice of References Cited (PTO-892) 2) Notice of Draftsperson's Patent Drawing Review (PTO-948 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SE Paper No(s)/Mail Date 4/27/05.) Paper No	Summary (PTO-413) (s)/Mail Date Informal Patent Application (PTO-152)			

Continuation of Disposition of Claims: Claims withdrawn from consideration are 3,5,6,8-13,15-17,20-55,58,60,61,64-72,75,77,78,81-83,117-124,128-131,133 and 134.

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DETAILED ACTION

Continued Examination Under 37 CFR 1.114

A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after allowance or after an Office action under *Ex Parte Quayle*, 25 USPQ 74, 453 O.G. 213 (Comm'r Pat. 1935). Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, prosecution in this application has been reopened pursuant to 37 CFR 1.114. Applicant's submission filed on 04/27/2005 has been entered.

Double Patenting

The nonstatutory double patenting rejection is based on a judicially created doctrine grounded in public policy (a policy reflected in the statute) so as to prevent the unjustified or improper timewise extension of the "right to exclude" granted by a patent and to prevent possible harassment by multiple assignees. See *In re Goodman*, 11 F.3d 1046, 29 USPQ2d 2010 (Fed. Cir. 1993); *In re Longi*, 759 F.2d 887, 225 USPQ 645 (Fed. Cir. 1985); *In re Van Ornum*, 686 F.2d 937, 214 USPQ 761 (CCPA 1982); *In re Vogel*, 422 F.2d 438, 164 USPQ 619 (CCPA 1970);and, *In re Thorington*, 418 F.2d 528, 163 USPQ 644 (CCPA 1969).

A timely filed terminal disclaimer in compliance with 37 CFR 1.321(c) may be used to overcome an actual or provisional rejection based on a nonstatutory double patenting ground provided the conflicting application or patent is shown to be commonly owned with this application. See 37 CFR 1.130(b).

Effective January 1, 1994, a registered attorney or agent of record may sign a terminal disclaimer. A terminal disclaimer signed by the assignee must fully comply with 37 CFR 3.73(b).

Claims 1-2, 14, 18-19, 56-57 and 63 are rejected under the judicially created doctrine of double patenting over claims 34 and 39 of U. S. Patent No. 6,784,480 since the claims, if allowed, would improperly extend the "right to exclude" already granted in the patent.

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The subject matter claimed in the instant application is fully disclosed in the patent and is covered by the patent since the patent and the application are claiming common subject matter, as follows: claims 34 in the patent discloses a first insulator region that functions as a tunnel medium; a floating plate as a charge storing medium that includes silicon nano crystals; and a second insulator region including Zirconium oxide that is a high K material and functions as a charge blocking (see Figure 17 of US 6,784,480) and claims 39 in the patent discloses an injector SRN layer disposed between the control gate and the high K charge blocking Zirconium oxide that inherently provides charge transport by enhanced tunneling.

Furthermore, there is no apparent reason why applicant was prevented from presenting claims corresponding to those of the instant application during prosecution of the application which matured into a patent. See *In re Schneller*, 397 F.2d 350, 158 USPQ 210 (CCPA 1968). See also MPEP § 804.

Claims 73-74, 80 and 84 are rejected under the judicially created doctrine of obviousness-type double patenting as being unpatentable over claims 34 and 39 of U.S. Patent No. 6,784,480. Although the conflicting claims are not identical, they are not patentably distinct from each other because '480 claims many of the same features in the claims of the pending application except the memory cell being used in an electronic system comprising a processor and a nonvolatile memory device coupled to the processor, the memory device including an array of memory cells coupled to a grid of row lines and column lines; row select circuitry and column select circuitry wherein the row select circuitry and the column select circuitry cooperate to select a memory cell for

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application of a programming voltage. A processor and a nonvolatile memory device coupled to the processor, the memory device including an array of memory cells coupled to a grid of row lines and column lines; row select circuitry and column select circuitry cooperated to select a memory cell for application of a programming voltage are conventional elements in a conventional electronic system. Therefore, it would have been obvious to form the memory cell of '480 as memory cells in the conventional electronic system having the conventional elements for the advantages that the memory cell of '480 provides.

Claims 4, 59 and 76 are rejected under the judicially created doctrine of obviousness-type double patenting as being unpatentable over claims of U.S. Patent No. 6,784,480 in view of Sadd et al. (US 6,444,545).

Bhattacharyya '480 claims many of the same features in the claims of the pending application except the tunnel medium including tunnel Al₂O₃. However, Al₂O₃, SiO₂ are dielectric material known in the art and routinely used as materials for tunnel medium in semiconductor devices as shown for example by Sadd et al. Therefore, it would have been obvious to one having ordinary skill in the art at then time the invention was made to select any one of these materials as a suitable dielectric material for the tunnel medium of Bhattacharyya '480 to provide good FN tunneling electroconductivity, since it has been held to be within the general skill of a worker in the art to select a known material on the basis of its suitability for the intended use as a matter of design choice. In re Leshin, 125 USPQ 416.

Allowable Subject Matter

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Claims 125-127 and 132 are allowed.

Conclusion

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Any inquiry concerning this communication or earlier communications from the examiner should be directed to Thien F. Tran whose telephone number is (571) 272-1665. The examiner can normally be reached on 8:30AM - 5:00PM Monday through Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Eddie C. Lee can be reached on (571) 272-1732. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

tt May 15, 2005

> THIEN TRAN PRIMARY EXAMINER